- Function and Pinout Compatible With FCT and F Logic
- 25-Ω Output Series Resistors to Reduce Transmission-Line Reflection Noise
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- 12-mA Output Sink Current
   15-mA Output Source Current
- 3-State Outputs

#### (TOP VIEW) 20 🛮 V<sub>CC</sub> T/R [ 19 N OE A<sub>0</sub> **[**]2 18 ∏ B<sub>0</sub> A<sub>1</sub> []3 17 🛮 B<sub>1</sub> A<sub>2</sub> 🛮 4 A<sub>3</sub> 🛮 5 16 **∏** B<sub>2</sub> A<sub>4</sub> [ 15 🛮 B<sub>3</sub> A<sub>5</sub> [ 14 ∏ B<sub>4</sub> A<sub>6</sub> 🛮 8 13 B<sub>5</sub> 12 🛮 B<sub>6</sub> A<sub>7</sub> **[]** 9 GND **1**10 11 B<sub>7</sub>

P, Q, OR SO PACKAGE

#### description

The CY74FCT2245T contains eight noninverting, bidirectional buffers with 3-state outputs intended for bus-oriented applications. On-chip termination resistors at the outputs reduce system noise caused by reflections. For this reason, the CY74FCT2245T can replace the CY74FCT245T in an existing design. The CY74FCT2245T current-sinking capability is 12 mA at the A and B ports.

The transmit/receive (T/R) input determines the direction of data flow through the bidirectional transceiver. Transmit (active high) enables data from A ports to B ports; receive (active low) enables data from B ports to A ports. The output-enable  $(\overline{OE})$  input, when high, disables both the A and B ports by putting them in the high-impedance state.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION

TA	PACI	KAGE <sup>†</sup>	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP - Q	QSOP – Q Tape and reel 4.1 CY74FCT2245CTQCT		CY74FCT2245CTQCT	FCT2245
	SOIC - SO	Tube	4.1	CY74FCT2245CTSOC	FCT2245
	3010 = 30	Tape and reel	4.1	CY74FCT2245CTSOCT	FC12245
DIP – F	DIP – P	Tube	4.6	CY74FCT2245ATPC	74FCT2245ATPC
-40°C to 85°C	QSOP - Q	Tape and reel	4.6	CY74FCT2245ATQCT	FCT2245A
-40 C to 65 C	SOIC - SO	Tube	4.6	CY74FCT2245ATSOC	FCT2245A
	3010 - 30	Tape and reel	4.6	CY74FCT2245ATSOCT	FC12245A
	QSOP - Q	Tape and reel	7.0	CY74FCT2245TQCT	FCT2245
	SOIC - SO	Tube	7.0	CY74FCT2245TSOC	FCT2245
	3010 - 30	Tape and reel	7.0	CY74FCT2245TSOCT	FG12240

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

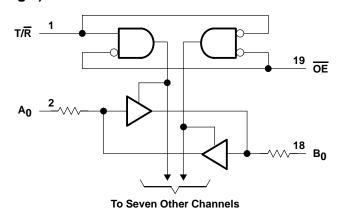


#### **FUNCTION TABLE**

INP	UTS	OUTPUT				
OE	T/R	OUTPUT				
L	L	Bus B data to bus A				
L	Н	Bus A data to bus B				
Н	Χ	Z				

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state

#### logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential		0.5 V to 7 V
DC input voltage range		0.5 V to 7 V
DC output voltage range		0.5 V to 7 V
DC output current (maximum sink current/pin)		120 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 1):	: P package	69°C/W
	Q package	68°C/W
	SO package	58°C/W
Ambient temperature range with power applied	i, T <sub>A</sub>	. −65°C to 135°C
Storage temperature range, T <sub>stg</sub>	• • • • • • • • • • • • • • • • • • • •	. −65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
٧ıH	High-level input voltage	2			V
$V_{IL}$	Low-level input voltage			0.8	V
loh	High-level output current			-15	mA
l <sub>OL</sub>	Low-level output current			12	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at  $V_{\hbox{\footnotesize{CC}}}$  or GND to ensure proper device operation.



# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION	s	MIN	TYP†	MAX	UNIT
VIK	$V_{CC} = 4.75,$	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2	V
VOH	$V_{CC} = 4.75,$	I <sub>OH</sub> = -15 mA		2.4	3.3		V
V <sub>OL</sub>	V <sub>CC</sub> = 4.75,	I <sub>OL</sub> = 12 mA			0.3	0.55	V
R <sub>out</sub>	$V_{CC} = 4.75,$	$I_{OL}$ = 12 mA		20	25	40	Ω
V <sub>hys</sub>	All inputs				0.2		V
lį	V <sub>CC</sub> = 5.25 V,	$V_{IN} = V_{CC}$				5	μΑ
lн	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 2.7 \text{ V}$				±1	μΑ
IΙL	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$				±1	μΑ
lozh	$V_{CC} = 5.25 \text{ V},$	V <sub>OUT</sub> = 2.7 V				10	μΑ
lozL	$V_{CC} = 5.25 \text{ V},$	V <sub>OUT</sub> = 0.5 V				-10	μΑ
los <sup>‡</sup>	$V_{CC} = 5.25 \text{ V},$	VOUT = 0 V		-60	-120	-225	mA
l <sub>off</sub>	$V_{CC} = 0 V$ ,	V <sub>OUT</sub> = 4.5 V				±1	μΑ
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
ΔlCC	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> =	3.4 V $\S$ , $f_1 = 0$ , Outputs op	oen		0.5	2	mA
I <sub>CCD</sub> ¶	$V_{\underline{CC}} = 5.25 \text{ V, One in}$ $T/R = \overline{OE} = GND, V_{\underline{I}}$	nput switching at 50% duty $N \le 0.2 \text{ V or V}_{10} \ge V_{CC} - 100 \text{ Jpc}$	y cycle, Outputs open, 0.2 V		0.06	0.12	mA/ MHz
		One input switching at f <sub>1</sub> = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	
I <sub>C</sub> #	V <sub>CC</sub> = 5.25 V,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1	2.4	mA
IC.,	T/R = OE = GND	Eight bits switching at f <sub>1</sub> = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$	1.3	2.6		
		at 50% duty cycle	V <sub>IN</sub> = 3.4 V or GND		3.3	10.6	
C <sub>i</sub>					5	10	pF
Co					9	12	pF

<sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

I<sub>C</sub> = Total supply current

ICC = Power-supply current with CMOS input levels

 $\Delta I_{CC}$  = Power-supply current for a TTL high input ( $V_{IN} = 3.4 \text{ V}$ )

D<sub>H</sub> = Duty cycle for TTL inputs high N<sub>T</sub> = Number of TTL inputs at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the I<sub>CC</sub> formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

 $<sup>\</sup>$  Per TTL-driven input ( $V_{IN} = 3.4 \text{ V}$ ); all other inputs at  $V_{CC}$  or GND

 $<sup>\</sup>P$  This parameter is derived for use in total power-supply calculations.

<sup>#</sup>  $I_{C}$  =  $I_{CC}$  +  $\Delta I_{CC}$  ×  $D_H$  ×  $N_T$  +  $I_{CCD}$  ( $f_0/2 + f_1$  ×  $N_1$ )
Where:

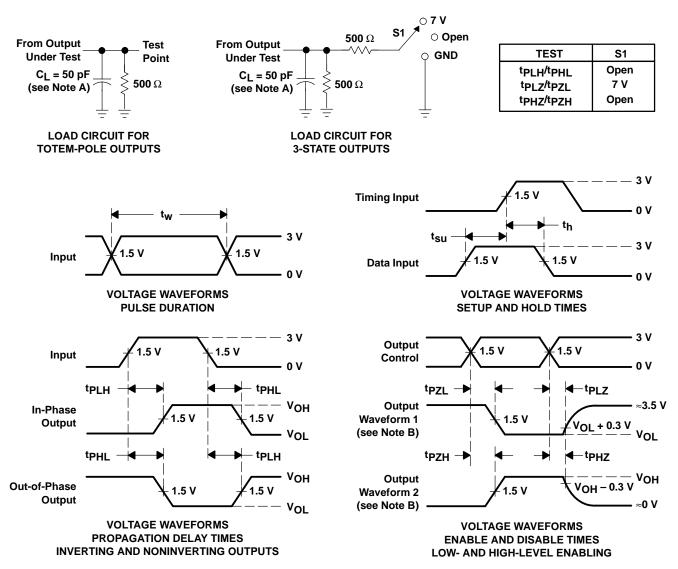
## CY74FCT2245T **8-BIT TRANSCEIVER** WITH 3-STATE OUTPUTS SCCS037B – JULY 1994 – REVISED NOVEMBER 2001

## switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	TO CY74FCT2245T		CY74FCT	2245AT	CY74FCT	UNIT	
PARAMETER	(INPUT)		MIN	MAX	MIN	MAX	MIN	MAX	UNII
t <sub>PLH</sub>	A <sub>n</sub> or B <sub>n</sub>	B <sub>n</sub> or A <sub>n</sub>	1.5	7	1.5	4.6	1.5	4.1	ns
<sup>t</sup> PHL	An or Bn	Dn or An	1.5	7	1.5	4.6	1.5	4.1	115
<sup>t</sup> PZH	ŌĒ	A or B	1.5	9.5	1.5	6.2	1.5	5.8	ns
t <sub>PZL</sub>	OE	AOIB	1.5	9.5	1.5	6.2	1.5	5.8	115
<sup>t</sup> PHZ	ŌĒ	A or B	1.5	7.5	1.5	5	1.5	4.5	no
t <sub>PLZ</sub>	OE	AUID	1.5	7.5	1.5	5	1.5	4.5	ns



#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74FCT2245ATSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2245ATSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2245CTSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2245CTSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATPC	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT2245ATPCE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT2245ATPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATQCT	ACTIVE	SSOP/ QSOP	DBQ	20		Green (RoHS & no Sb/Br)		Level-2-260C-1 YEAR
CY74FCT2245ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20		Green (RoHS & no Sb/Br)		Level-2-260C-1 YEAR
CY74FCT2245ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2245ATSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245ATSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245CTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2245CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2245CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2245CTSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2245TQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2245TSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



#### PACKAGE OPTION ADDENDUM

www.ti.com 11-Nov-2009

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CY74FCT2245TSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2245TSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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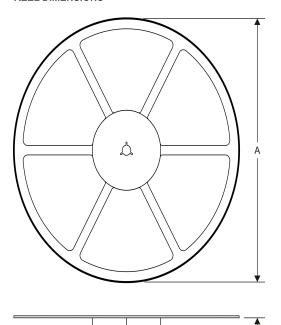
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## PACKAGE MATERIALS INFORMATION

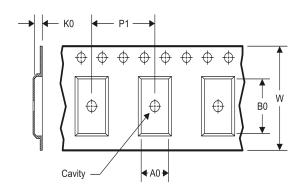
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#### TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



#### **TAPE DIMENSIONS**



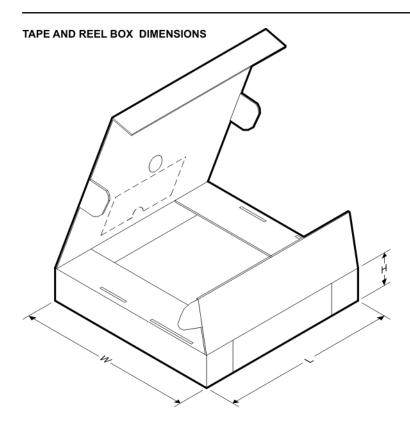
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

\*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2245ATPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
CY74FCT2245ATQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2245ATSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT2245CTQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2245CTSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT2245TQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2245TSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT2245ATPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
CY74FCT2245ATQCT	SSOP/QSOP	DBQ	20	2500	367.0	367.0	38.0
CY74FCT2245ATSOCT	SOIC	DW	20	2000	367.0	367.0	45.0
CY74FCT2245CTQCT	SSOP/QSOP	DBQ	20	2500	367.0	367.0	38.0
CY74FCT2245CTSOCT	SOIC	DW	20	2000	367.0	367.0	45.0
CY74FCT2245TQCT	SSOP/QSOP	DBQ	20	2500	367.0	367.0	38.0
CY74FCT2245TSOCT	SOIC	DW	20	2000	367.0	367.0	45.0

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

#### PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DBQ (R-PDSO-G20)

## PLASTIC SMALL-OUTLINE PACKAGE

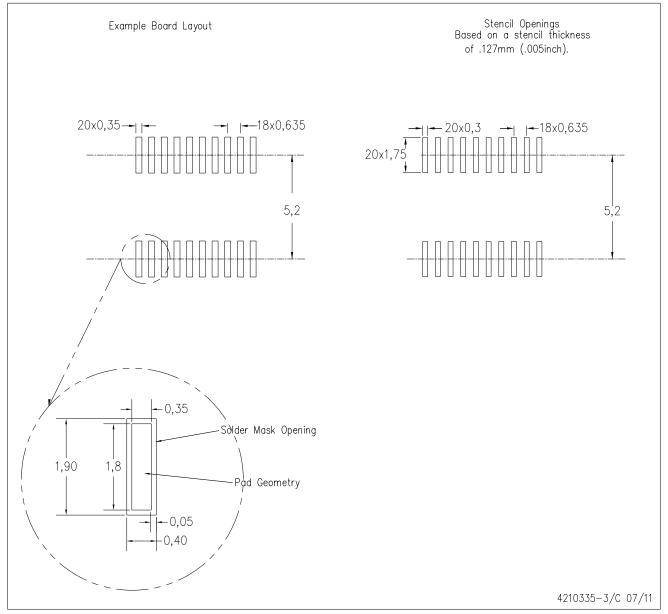


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



## DBQ (R-PDSO-G20)

## PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



PW (R-PDSO-G20)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



## PW (R-PDSO-G20)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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